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## ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

<b>Title of Invention</b>	<b>SELECTIVE SILICON-ON-INSULATOR ISOLATION STRUCTURE AND METHOD</b>
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Application Number:

Confirmation Number:

First Named Applicant: An Steegan

Attorney Docket Number: FIS920030051

Search string: ( 6429091 or 5153813 or 4849376 or 20020185469 ).pn.

**US Patent Documents**

Note: Applicant is not required to submit a paper copy of cited US Patent Documents


init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
9K	1	6429091	2002-08-06	Chen et al.		438	423
MY	2	5153813	1992-10-06	Oehrlein et al.		361	313
MX	3	4849376	1989-07-18	Balzan et al.		438	582

**US Published Applications**

Note: Applicant is not required to submit a paper copy of cited US Published Applications

init	Cite.No.	Pub. No.	Date	Applicant	Kind	Class	Subclass
9K	1	20020185469	2002-12-12	Podlesnik et al.		216	41

**Signature**

<b>Examiner Name</b>	<b>Date</b>
	9/30/04